



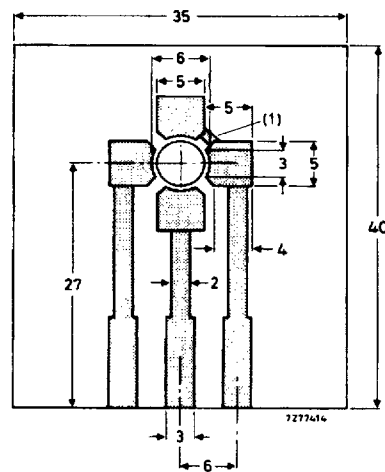
**RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Drain-source voltage	$V_{DS}$	max.	20 V
Drain current (DC or average)	$I_D$	max.	20 mA
Gate 1 - source current	$\pm I_{G1-S}$	max.	10 mA
Gate 2 - source current	$\pm I_{G2-S}$	max.	10 mA
Total power dissipation up to $T_{amb} = 75\text{ }^\circ\text{C}$	$P_{tot}$	max.	225 mW
Storage temperature range	$T_{stg}$		-65 to + 150 $^\circ\text{C}$
Junction temperature	$T_j$	max.	150 $^\circ\text{C}$

**THERMAL RESISTANCE**

From junction to ambient in free air mounted on the printed-circuit board (see Fig.2)	$R_{thj-a}$	=	335 K/W
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Dimensions in mm

(1) Connection made by a strip or Cu wire.

Fig. 2 Single-sided 35  $\mu\text{m}$  Cu-clad epoxy fibre-glass printed-circuit board, thickness 1,5 mm. Tracks are fully tin-lead plated. Board in horizontal position for  $R_{th}$  measurement.

**STATIC CHARACTERISTICS** $T_j = 25\text{ }^\circ\text{C}$ 

## Gate cut-off currents

$\pm V_{G1-S} = 5\text{ V}; V_{G2-S} = V_{DS} = 0$	$\pm I_{G1-SS}$	<	25 nA
$\pm V_{G2-S} = 5\text{ V}; V_{G1-S} = V_{DS} = 0$	$\pm I_{G2-SS}$	<	25 nA

## Gate-source breakdown voltages

$\pm I_{G1-SS} = 10\text{ mA}; V_{G2-S} = V_{DS} = 0$	$\pm V_{(BR)G1-SS}$	6 to 20 V
$\pm I_{G2-SS} = 10\text{ mA}; V_{G1-S} = V_{DS} = 0$	$\pm V_{(BR)G2-SS}$	6 to 20 V

## Drain current

$V_{DS} = 10\text{ V}; V_{G1-S} = 0; +V_{G2-S} = 4\text{ V}$	$I_{DSS}$	4 to 25 mA
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## Gate-source cut-off voltages

$I_D = 20\text{ }\mu\text{A}; V_{DS} = 10\text{ V}; +V_{G2-S} = 4\text{ V}$	$-V_{(P)G1-S}$	<	2.5 V
$I_D = 20\text{ }\mu\text{A}; V_{DS} = 10\text{ V}; V_{G1-S} = 0$	$-V_{(P)G2-S}$	<	2.5 V

**DYNAMIC CHARACTERISTICS**Measuring conditions (common source):  $I_D = 10\text{ mA}; V_{DS} = 10\text{ V}; +V_{G2-S} = 4\text{ V}; T_{amb} = 25\text{ }^\circ\text{C}$ 

Transfer admittance at $f = 1\text{ kHz}$	$ y_{fs} $	>	10 mS
		typ.	14 mS
Input capacitance at gate 1; $f = 1\text{ MHz}$	$C_{ig1-s}$	typ.	2.1 pF
Input capacitance at gate 2; $f = 1\text{ MHz}$	$C_{ig2-s}$	typ.	1.0 pF
Feedback capacitance at $f = 1\text{ MHz}$	$C_{rs}$	typ.	20 fF
Output capacitance at $f = 1\text{ MHz}$	$C_{os}$	typ.	1.1 pF
Noise figure at $f = 100\text{ MHz}; G_S = 1\text{ mS}; B_S = B_S\text{ opt}$	F	typ.	0.7 dB
		<	1.7 dB
Noise figure at $f = 200\text{ MHz}; G_S = 2\text{ mS}; B_S = B_S\text{ opt}$	F	typ.	1.0 dB
		<	2.0 dB
Transducer gain at $f = 100\text{ MHz}; G_S = 1\text{ mS}; B_S = B_S\text{ opt};$ $G_L = 0.5\text{ mS}; B_L = B_L\text{ opt}$	$G_{tr}$	typ.	29 dB
Transducer gain at $f = 200\text{ MHz}; G_S = 2\text{ mS}; B_S = B_S\text{ opt};$ $G_L = 0.5\text{ mS}; B_L = B_L\text{ opt}$	$G_{tr}$	typ.	26 dB

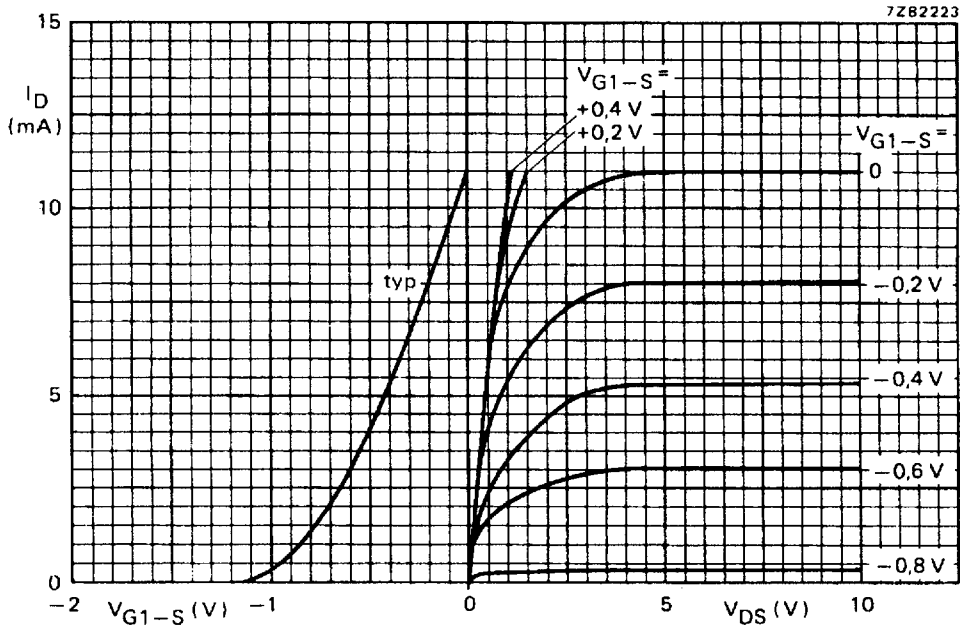


Fig. 3 Left-hand graph:  $V_{DS} = 10\text{ V}$ ;  $V_{G2-S} = +4\text{ V}$ ;  $T_{amb} = 25\text{ }^\circ\text{C}$ . Right-hand graph:  $V_{G2-S} = +4\text{ V}$ ;  $T_{amb} = 25\text{ }^\circ\text{C}$ .

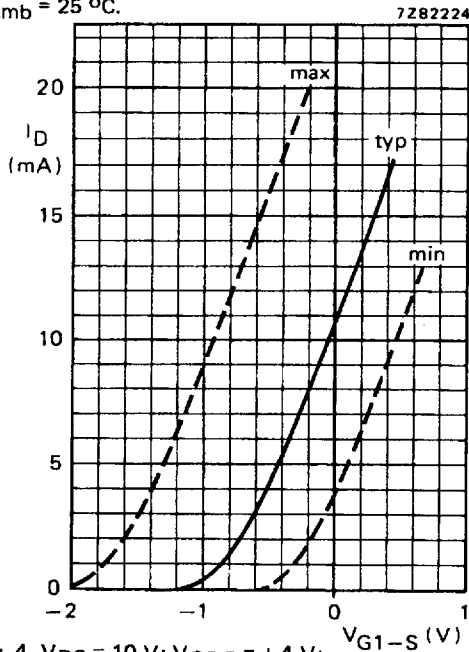


Fig. 4  $V_{DS} = 10\text{ V}$ ;  $V_{G2-S} = +4\text{ V}$ ;  $T_{amb} = 25\text{ }^\circ\text{C}$ .

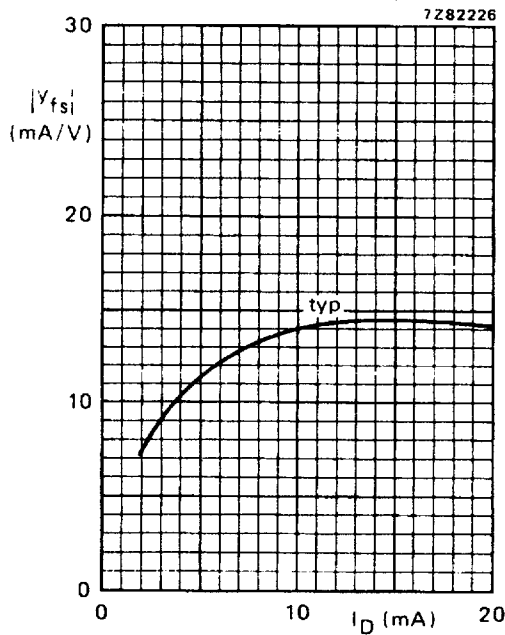
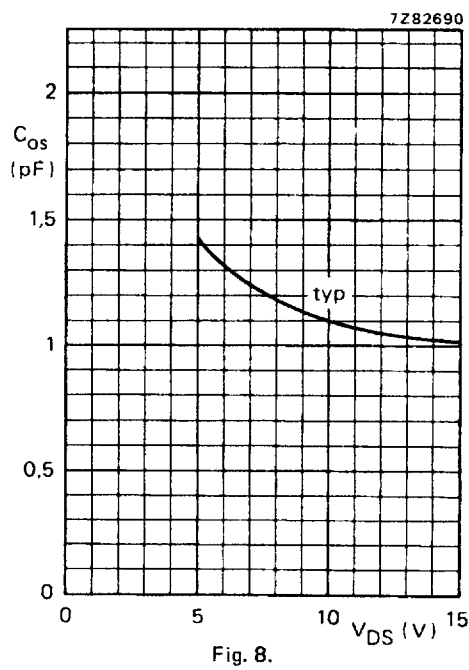
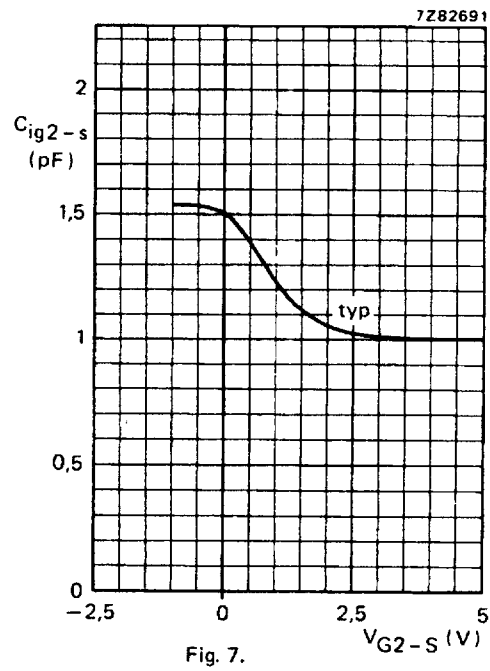
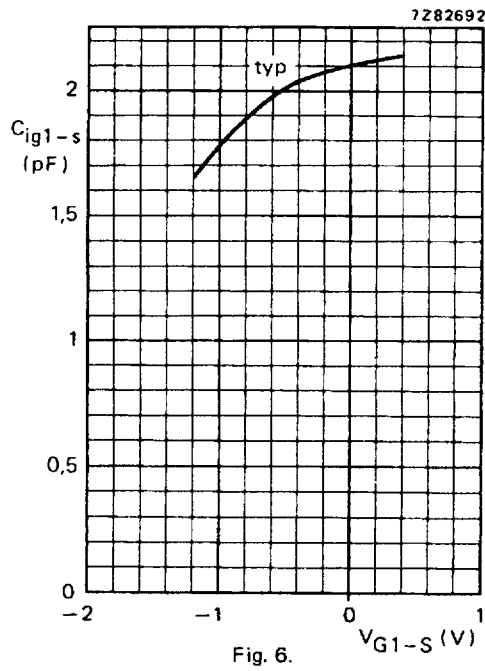


Fig. 5  $V_{DS} = 10\text{ V}$ ;  $V_{G2-S} = +4\text{ V}$ ;  $f = 1\text{ kHz}$ ;  $T_{amb} = 25\text{ }^\circ\text{C}$ .



## Measuring conditions:

Fig. 6  $V_{DS} = 10$  V;  $V_{G2-s} = +4$  V;  $f = 1$  MHz;  
 $T_{amb} = 25$  °C.

Fig. 7  $V_{DS} = 10$  V;  $V_{G1-s} = 0$ ;  $f = 1$  MHz;  
 $T_{amb} = 25$  °C.

Fig. 8  $V_{G2-s} = +4$  V;  $I_D = 10$  mA;  $f = 1$  MHz;  
 $T_{amb} = 25$  °C.

Measuring conditions for Figs 9 to 12:  $V_{DS} = 10 \text{ V}$ ;  $I_D = 10 \text{ mA}$ ;  $V_{G2-S} = +4 \text{ V}$ ;  $T_{amb} = 25 \text{ }^\circ\text{C}$ .

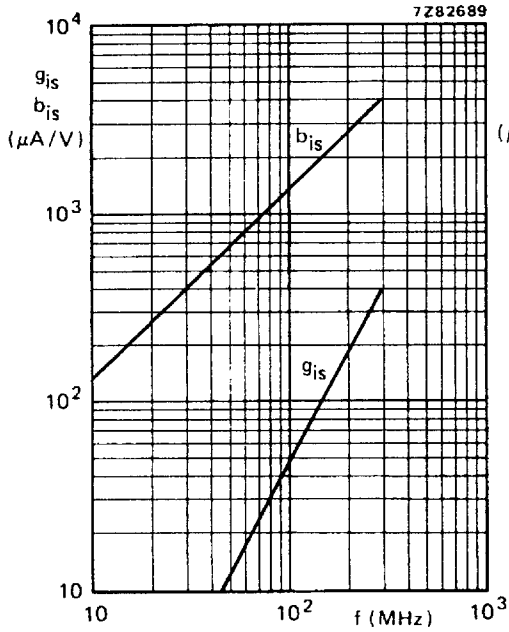


Fig. 9.

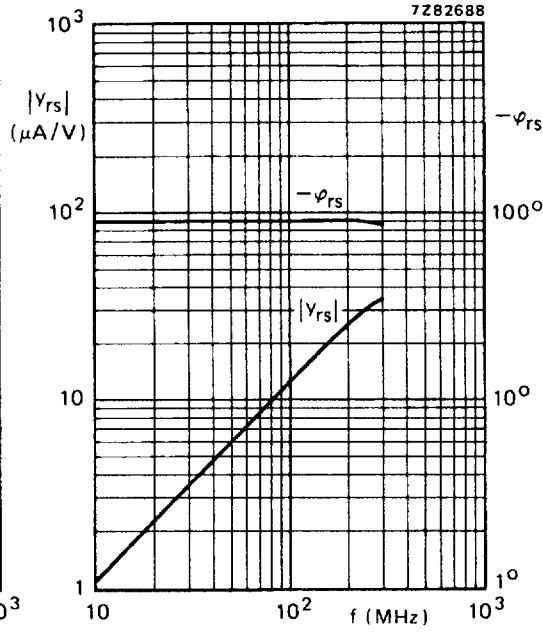


Fig. 10.

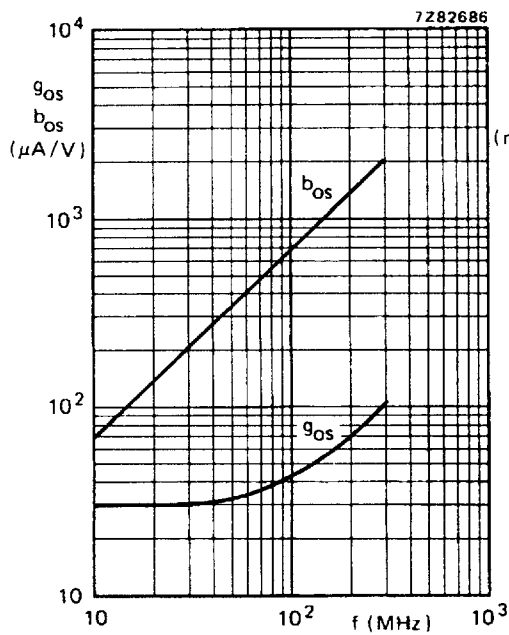


Fig. 11.

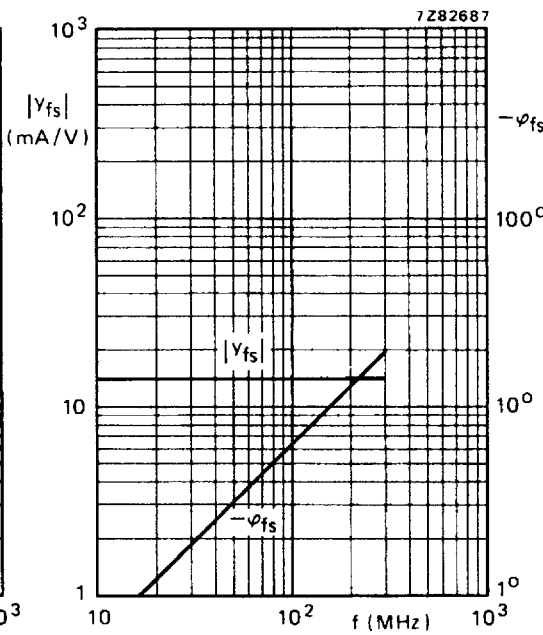


Fig. 12.

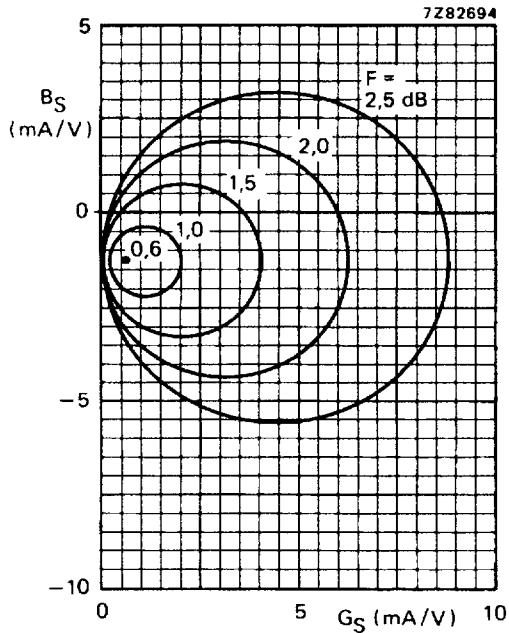


Fig. 13  $V_{DS} = 10$  V;  $V_{G2-S} = +4$  V;  $I_D = 10$  mA;  $f = 100$  MHz;  $T_{amb} = 25$  °C; circles of typical constant noise figures.

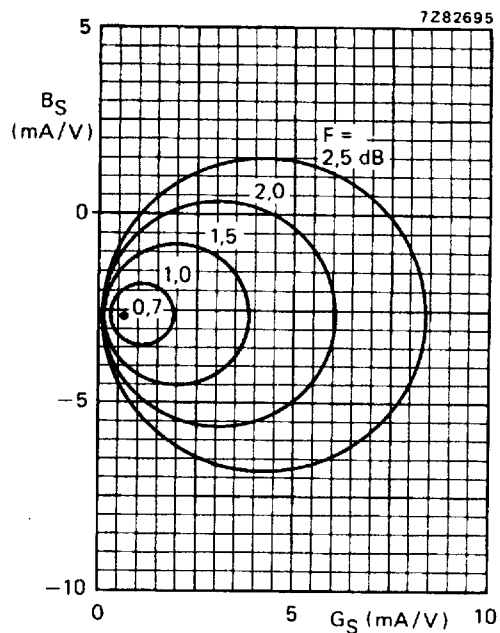


Fig. 14  $V_{DS} = 10$  V;  $V_{G2-S} = +4$  V;  $I_D = 10$  mA;  $f = 200$  MHz;  $T_{amb} = 25$  °C; circles of typical constant noise figures.

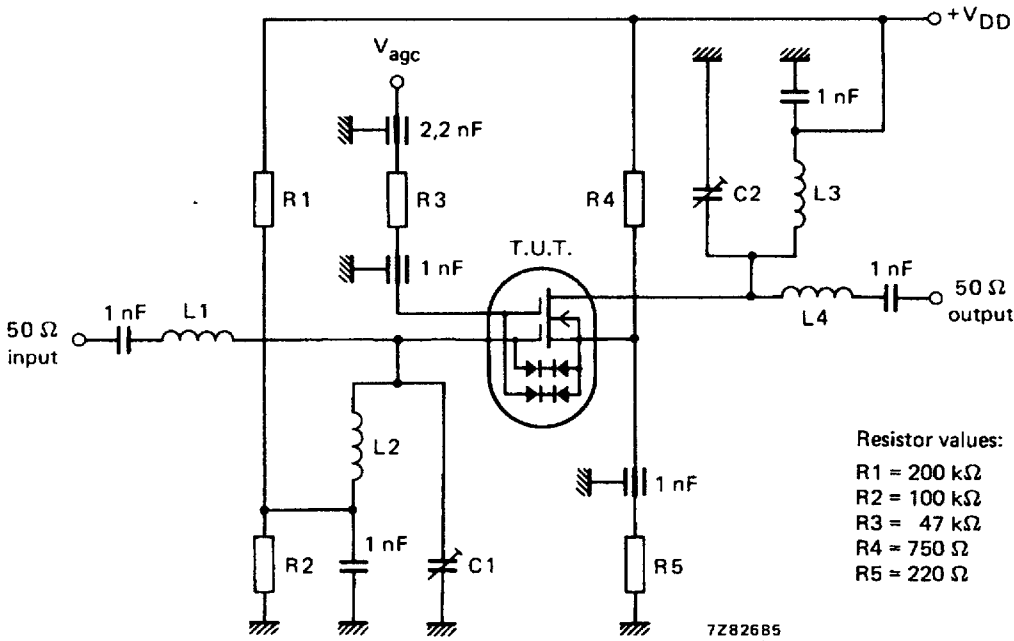


Fig. 15 Automatic gain control test circuit at  $f = 200$  MHz (see also Fig. 16).  
 $V_{DD} = 16$  V;  $G_S = 2$  mA/V;  $G_L = 0,5$  mA/V.

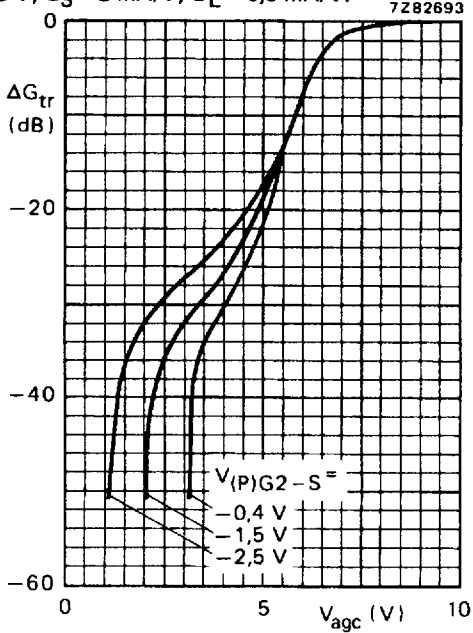


Fig. 16  $V_{DD} = 16$  V;  $f = 200$  MHz;  
 $T_{amb} = 25$   $^{\circ}$ C; typical values;  
 see also Fig. 15.